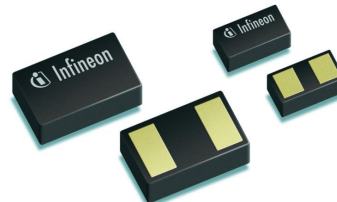


Silicon TVS Diode

- ESD / transient protection of data and power lines in low voltage applications according to:
IEC61000-4-2 (ESD): ± 25 kV (air) 20 kV (contact)
IEC61000-4-4 (EFT): 50 A / 2.5 kV (5/50 ns)
IEC61000-4-5 (surge): 5.5 A / 80 W (8/20 μ s)
- Small form factor (0402 inch):
1.0 x 0.6 x 0.4 mm³
- Bi-directional, symmetrical
working voltage up to ± 5.3 V
- Ultralow and symmetric clamping voltage
- Ultralow dynamic resistance **0.4 Ω**
- Very fast response time
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101



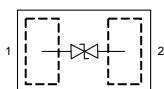
Applications

Recommended to protect audio lines /
microphone lines / speaker and
headset systems in:

- Mobile phones
- Mobile TV
- Set top boxes
- MP3 players
- Minidisc players
- Portable entertainment electronics



ESD5V3S1B-02LRH



Type	Package	Configuration	Marking
ESD5V3S1B-02LRH	TSLP-2-17	1 line, bi-directional	E1

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD air / contact discharge ¹⁾	V_{ESD}	25 / 20	kV
Peak pulse current ($t_p = 8 / 20 \mu\text{s}$) ²⁾	I_{pp}	5.5	A
Peak pulse power ($t_p = 8 / 20 \mu\text{s}$) ²⁾	P_{pk}	80	W
Operating temperature range	T_{op}	-55...125	$^\circ\text{C}$
Storage temperature	T_{stg}	-65...150	

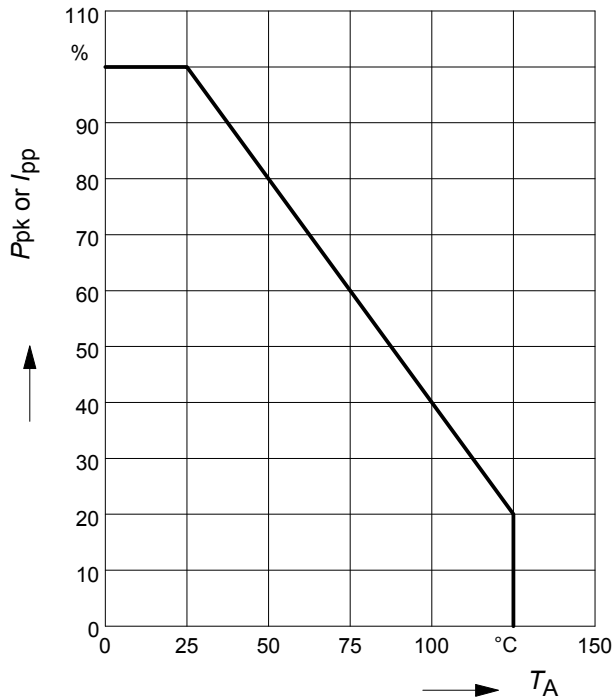
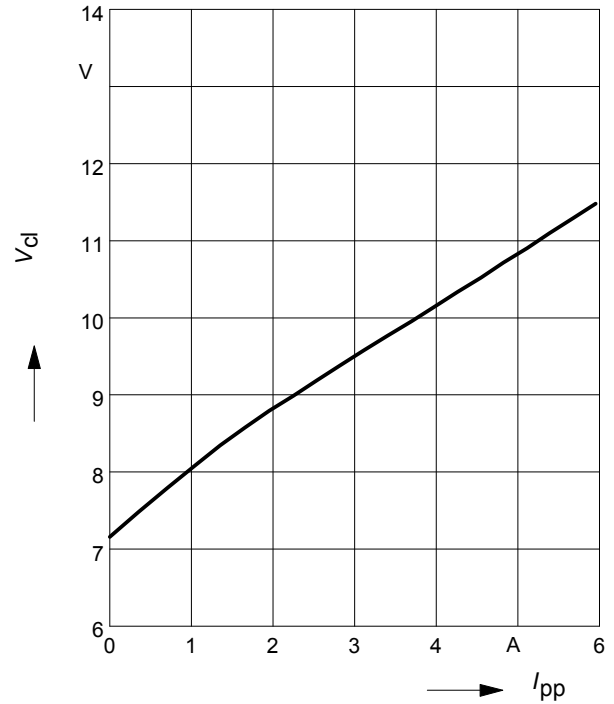
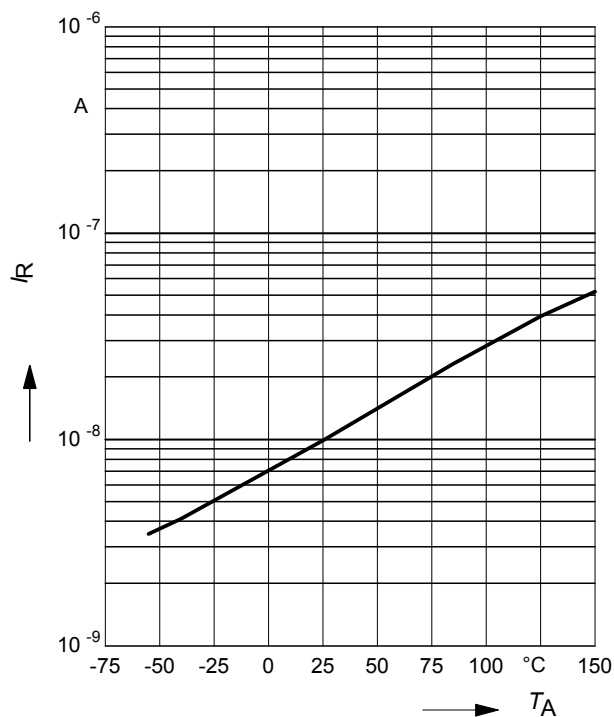
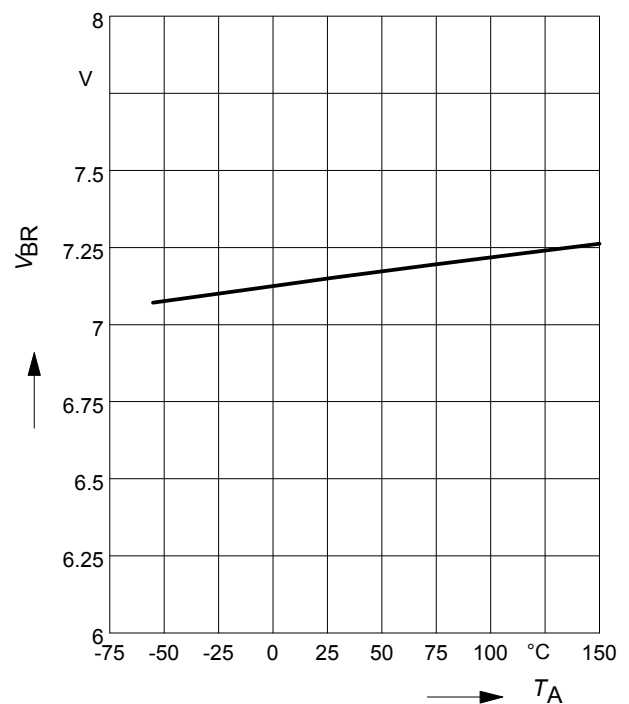
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics					
Reverse working voltage	V_{RWM}	-5.3	-	5.3	V
Breakdown voltage $I_{\text{(BR)}} = 1 \text{ mA}$	$V_{\text{(BR)}}$	6	-	-	
Reverse current $V_{\text{R}} = 3.3 \text{ V}$	I_{R}	-	-	0.1	μA
Clamping voltage $I_{\text{PP}} = 1 \text{ A}, t_{\text{p}} = 8/20 \text{ }\mu\text{s}^2)$ $I_{\text{PP}} = 3.5 \text{ A}, t_{\text{p}} = 8/20 \text{ }\mu\text{s}^2)$ $I_{\text{PP}} = 5.5 \text{ A}, t_{\text{p}} = 8/20 \text{ }\mu\text{s}^2)$	V_{CL}	- - -	8 10 11	10 12 13	V
Diode capacitance $V_{\text{R}} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{\text{R}} = 2.5 \text{ V}, f = 1 \text{ MHz}$	C_{T}	- -	17.5 14.5	20 -	
Dynamic resistance ³⁾ ($t_{\text{p}} = 30 \text{ ns}$)	R_{D}	-	0.4	-	Ω

¹⁾ V_{ESD} according to IEC61000-4-2

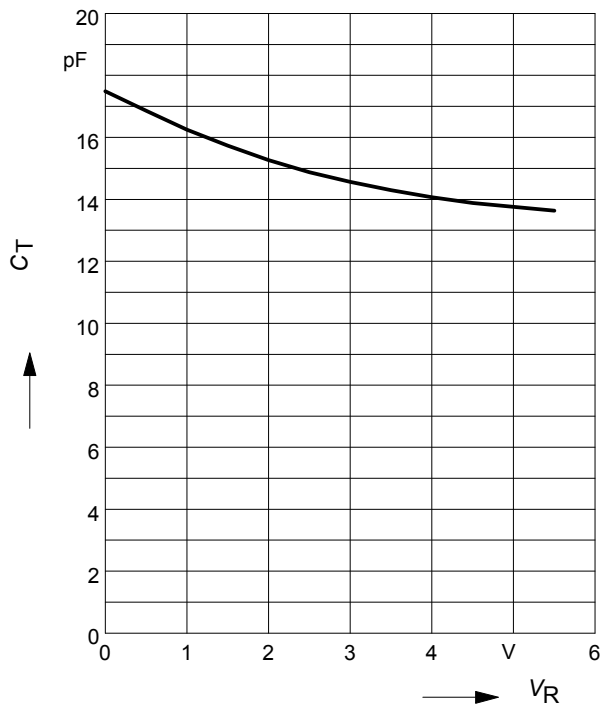
²⁾ I_{pp} according to IEC61000-4-5

³⁾ according to TLP tests

Power derating curve $P_{pk} = f(T_A)$

Clamping voltage, $V_{cl} = f(I_{pp})$
 $t_p = 8 / 20 \mu s$

Reverse current $I_R = f(T_A)$
 $V_R = 3.3 V$

Breakdown voltage $V_{BR} = f(T_A)$
 $I_R = 1 mA$


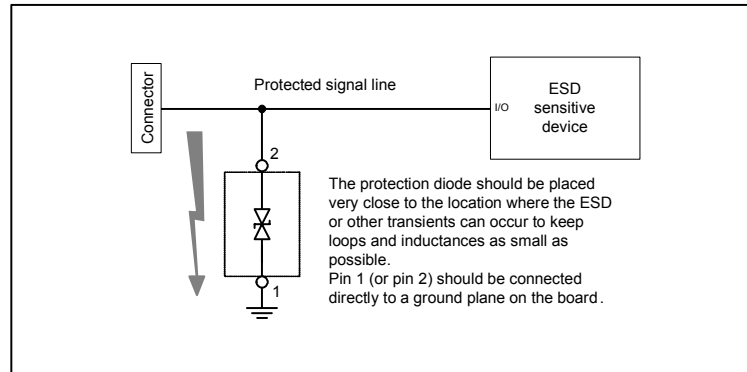
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$

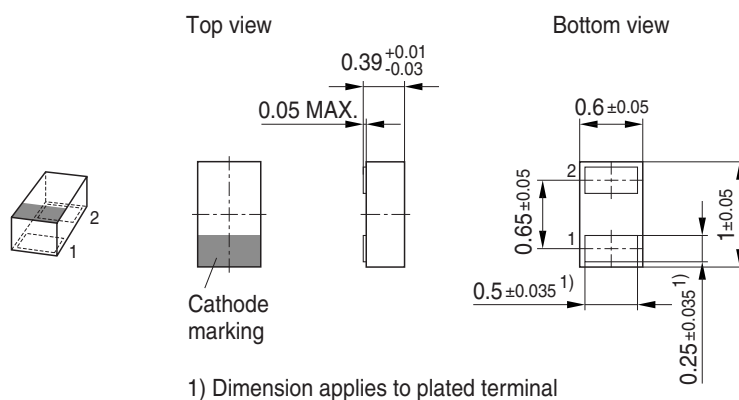


Application example

single channel, bi-directional

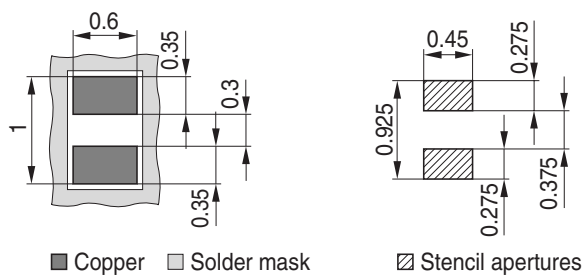


Package Outline

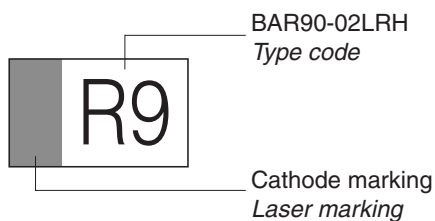


Foot Print

For board assembly information please refer to Infineon website "Packages"



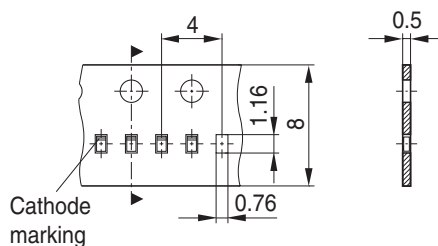
Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel

Reel ø330 mm = 50.000 Pieces/Reel (optional)



Edition 2009-11-16

**Published by
Infineon Technologies AG
81726 Munich, Germany**

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